

DATE: December 14, 1996
 TO: J. Lohr/311.1
 FROM: K. Sahu/300.1 *K. Sahu*
 SUBJECT: Radiation Report on: DAC87
 Project: ASTRO-L/XDS
 Control #: 15405
 Job #: EE62006

PPM-97-004

cc: A. Sharma/311
OFA Library/300.1

A radiation evaluation was performed on DAC87 (12-bit D/A Converter) to determine the total dose tolerance of these parts. A brief summary of the test results is provided below. For detailed information, refer to Figure 1 and Tables I through IV.

The total dose testing was performed using a Co⁶⁰ gamma ray source. During the radiation testing, four parts were irradiated under bias (see Figure 1 for bias configuration) and one part was used as a control sample. The total dose radiation levels were 1, 3, 5, 10, 20, 50 and 100 krads*. The dose rate was between 30 and 1760 rads/hour, depending on the total dose level (see Table II for radiation schedule). After the final radiation exposures, parts were annealed for 336 hours @ 25°C and for 168 hours @ 100°C. After each radiation exposure and annealing step, parts were electrically tested according to the test conditions and the specification limits'' listed in Table III.

All parts passed all initial electrical tests. All parts passed all electrical tests throughout all irradiation steps.

No significant degradation was observed in any parameter throughout all irradiation and annealing steps.

Table IV provides mean and standard deviation values for each parameter initially and after each irradiation exposure.

Any further details about this evaluation can be obtained upon request. If you have any questions, please call me at (301) 731-8954.

* The term rads, as used in this document, means rads(SiO₂). All consecutive annealing times at the same temperature and all radiation levels cited are cumulative.

** These are manufacturer's pre-irradiation data specification limits. No post-irradiation limits were provided by the manufacturer at the time these tests were performed.

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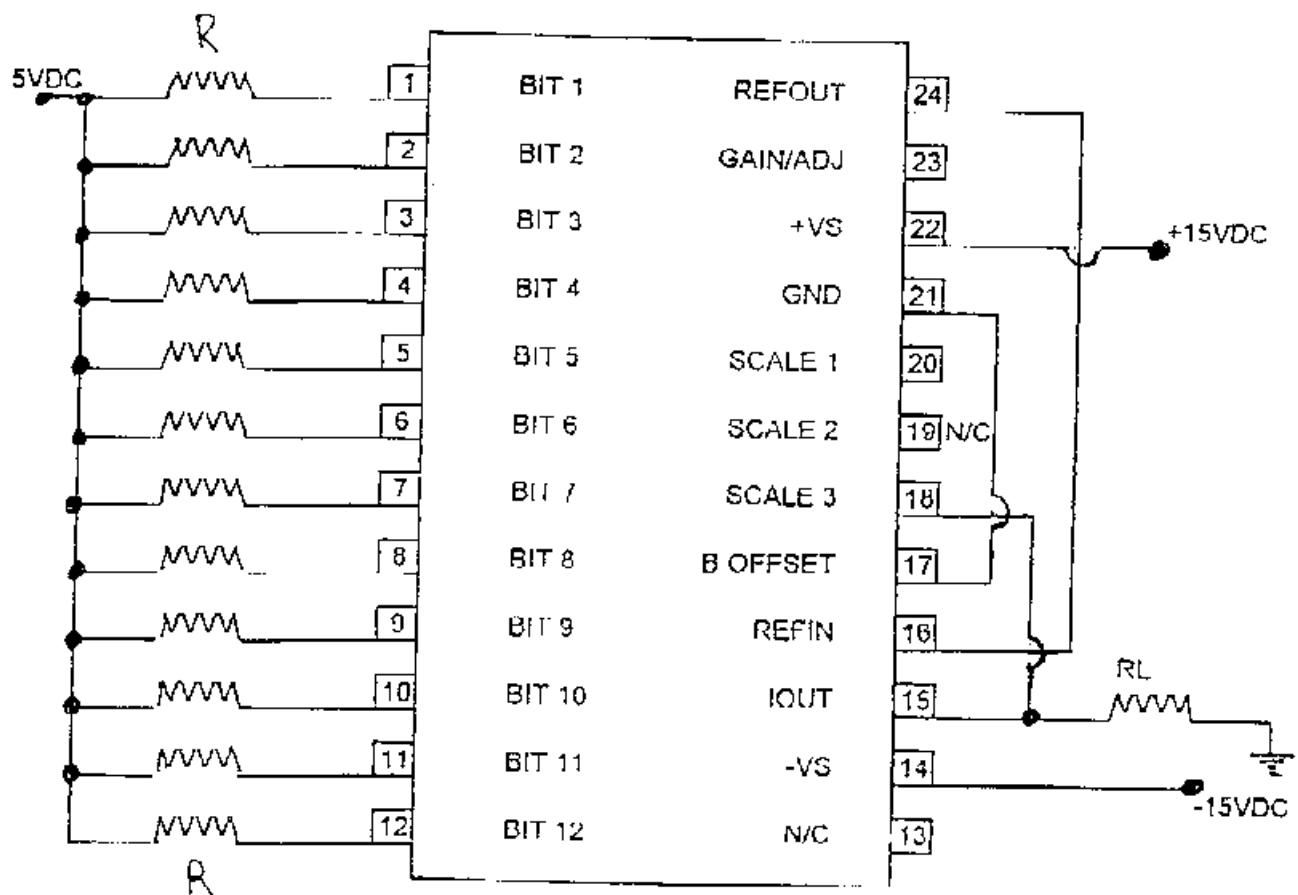
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Figure 1. Radiation Bias Circuit for DAC87

ADDA87
12 BIT D/A CONVERTER

RADIATION BIAS CIRCUIT



All R's are 10K ohms.
 $\frac{1}{4}W$
 5%
 $RL = 5K \text{ ohms}$

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TABLE I. Part Information

Generic Part Number:	DAC87
ASTRO-I/XDS Part Number:	ADDAC87D CB1-V/883
ASTRO-E/XDS Control Number:	15405
Charge Number:	EE62006
Manufacturer:	Analog Devices
Lot Date Code (LDC):	9445L, 9432A
Quantity Tested:	6
Serial Number of Control Sample:	182
Serial Numbers of Radiation Samples:	183, 184, 185, 186
Part Function:	12-bit D/A Converter
Part Technology:	Hybrid
Package Style:	24-pin DIP
Test Equipment:	A540
Engineer:	A. Duvalsaint

* No radiation tolerance/hardness was guaranteed by the manufacturer for this part.

TABLE II. Radiation Schedule for DAC87

EVENT	DATE
1) INITIAL ELECTRICAL MEASUREMENTS.....	10/22/96
2) 1 KRAD IRRADIATION (0.06 KRADS/HOUR).....	10/22/96
POST-1 KRAD ELECTRICAL MEASUREMENT	10/23/96
3) 3 KRAD IRRADIATION (0.03 KRADS/HOUR).....	11/01/96
POST-3 KRAD ELECTRICAL MEASUREMENT.....	11/04/96
4) 5 KRAD IRRADIATION (0.12 KRADS/HOUR).....	11/04/96
POST-5 KRAD ELECTRICAL MEASUREMENT.....	11/05/96
5) 10 KRAD IRRADIATION (0.29 KRADS/HOUR).....	11/05/96
POST-10 KRAD ELECTRICAL MEASUREMENT.....	11/06/96
6) 144-HOUR ANNEALING @25°C	11/06/96
POST-144 HOUR ANNEAL ELECTRICAL MEASUREMENT	11/12/96
7) 20 KRAD IRRADIATION (0.59 KRADS/HOUR)	11/12/96
POST-20 KRAD ELECTRICAL MEASUREMENT.....	11/13/96
8) 50 KRAD IRRADIATION (1.76 KRADS/HOUR)	11/13/96
POST-50 KRAD ELECTRICAL MEASUREMENT.....	11/14/96
9) 100 KRAD IRRADIATION (0.56 KRADS/HOUR)	11/14/96
POST-100 KRAD ELECTRICAL MEASUREMENT.....	11/18/96
0) 336 HOURS ANNEALING @25°C	11/19/96
POST 336 HOURS ANNEALING ELECTRICAL MEASUREMENT	12/03/96
11) 168 HOURS ANNEALING @100°C	12/03/96
POST 168 HOURS ANNEALING ELECTRICAL MEASUREMENT	12/10/96

* PARTS WERE IRRADIATED AND ANNEALED UNDER BIAS; SEE FIGURE 1.

Table III. Electrical Characteristics of DAC87

Unipolar +10V Mode				
	Electrical		Spec. Lim./1	
#	Parameters	Units	min	max
1	Icc	mA	-	10
2	lee	mA	-20	-
3	Vref	V	6.23	6.37
8	Iih B1 /2	µA	-	250
20	Iil B1 /3	µA	-100	-
32	Lin_Error	lsb	-0.5	0.5
33	Dif_LinErr	lsb	-0.5	0.75
Bipolar +/-10V Mode				
	Electrical		Spec. Lim./1	
#	Parameters	Units	min	max
34	Lin_Error	lsb	-0.5	0.5
35	Dif_LinErr	lsb	-0.75	0.75

**TABLE IV: Summary of Electrical Measurements after
Total Dose Exposures and Annealing for DAC87**

Unipolar -1BV Mode		Total Dose Exposure (kRads)												Annealing				Annealing 4'						
Electrical	Spec L.m.s.t	Initial				144 hrs. @ 15°C				20				50				100				168 hrs. @ 25°C		
		# Parameters	Units	min	max	mean	sd	mean	sd	mean	sd	mean	sd	mean	sd	mean	sd	mean	sd	mean	sd	mean	sd	
1	Icc	mA	-	10	5.35	.09	5.35	.09	5.35	.09	5.35	.09	5.35	.09	5.35	.09	5.35	.09	5.35	.09	5.27	.09	5.2	.09
2	Iee	mA	-20	-	-14.1	.29	-14.1	.29	-14.1	.29	-14.1	.29	-14.1	.29	-14.1	.29	-13.9	.29	-13.9	.29	-13.5	.30	-	-
3	Vref	V	6.23	6.37	6.299	0	6.299	0	6.299	0	6.299	0	6.299	0	6.299	0	6.299	0	6.300	0	6.300	0	6.295	.01
8	Ith_B1/2	µA	-	250	150	4.8	150	4.8	150	4.8	150	4.8	150	4.8	150	4.8	150	4.8	150	4.8	150	5.2	145	4.5
20	Ith_B1/3	µA	-100	-	39.4	1.5	39.4	1.5	39.4	1.5	39.4	1.5	39.4	1.5	39.4	1.5	39.4	1.5	38.8	1.3	38.8	1.3	38.5	1.2
32	Lin_Error	lsb	-0.5	0.5	0.03	.06	0.03	.06	0.03	.06	0.03	.06	0.03	.06	0.03	.06	0.03	.06	0.05	.05	0.05	.05	.06	.05
33	Dif_LinErr	lsb	-0.5	0.75	-0.08	.01	-0.08	.01	-0.08	.01	-0.08	.01	-0.08	.01	-0.08	.01	-0.08	.01	-0.08	.01	-0.08	.01	.07	.01
Bipolar -1BV Mode		Total Dose Exposure (kRads)												Annealing				Annealing 4'						
Electrical	Spec L.m.s.t	Initial				144 hrs. @ 15°C				20				50				168 hrs. @ 25°C						
# Parameters	Units	min	max	mean	sd	mean	sd	mean	sd	mean	sd	mean	sd	mean	sd	mean	sd	mean	sd	mean	sd	mean	sd	
34	Ith_Firrr	lsb	-0.5	0.5	0.09	.04	0.09	.04	0.09	.04	0.09	.04	0.09	.04	0.09	.04	0.09	.04	0.09	.04	0.09	.02	.09	.02
35	Dif_IthFirrr	lsb	-0.75	0.75	0.09	.01	-0.09	.01	-0.09	.01	-0.09	.01	-0.09	.01	-0.09	.01	-0.09	.01	-0.09	.01	-0.09	.01	.09	.01

Notes:

1/ These are manufacturer's pre-irradiation data sheet specification limits. No post-irradiation limits were provided by the manufacturer at the time these tests were performed.

2/ This is a typical reading for all Ith tests throughout all irradiation and annealing steps.

Detailed data for Ith_B2 - Ith_B12 are available on request.

3/ This is a typical reading for all Ith tests throughout all irradiation and annealing steps.

Detailed data for Ith_B2 - Ith_B12 are available on request.

4/ The test data for all electrical parameters after high temperature annealing was very similar to the measurements after R.T. annealing and is therefore not included in this table. This data is available on request.